

GP1A50HRJ00F

Gap: 3mm, Slit: 0.5mm *OPIC Output Case package Transmissive **Photointerrupter**



Description

GP1A50HRJ00F is a standard, OPIC output, transmissive photointerrupter with opposing emitter and detector in a case, providing non-contact sensing. For this family of devices, the emitter and detector are inserted in a case, resulting in a through-hole design.

The case is unique because it uses additional screw fixing holes, on both sides 3.2mm diameter, and the shape prevents miss-orientation.

■ Features

- 1. Transmissive with OPIC output
- 2. Highlights:
 - Verical Slit for alternate motion detection
 - Output Low Level at intercepting optical path
 - · Includes additional screw fixing holes
- 3. Key Parameters:
 - · Gap Width: 3mm
 - · Slit Width (detector side): 0.5mm
 - Package : 25×10×6 mm
- 4. Lead free and RoHS directive compliant

■ Agency approvals/Compliance

1. Compliant with RoHS directive

■Applications

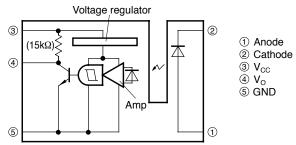
- 1. General purpose detection of object presence or motion.
- 2. Example: Printer, FAX, Optical storage unit

^{* &}quot;OPIC"(Optical IC) is a trademark of the SHARP Corporation. An OPIC consists of a light-detecting element and a signalprocessing



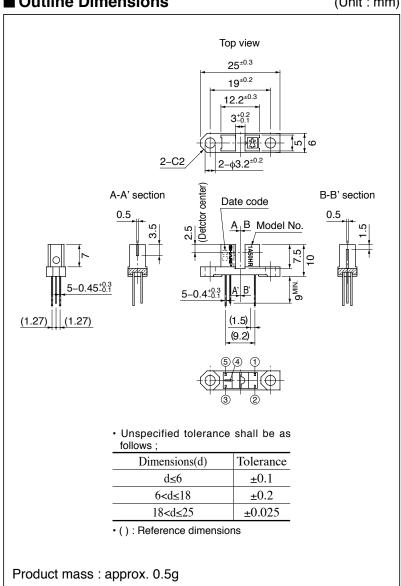
■ Internal Connection Diagram

Top view



■ Outline Dimensions

(Unit: mm)



Dip soldering material: Sn-3Ag-0.5Cu



Date code (2 digit)				
1st digit		2nd digit		
Year of production		Month of production		
A.D.	Mark	Month	Mark	
2000	0	1	1	
2001	1	2	2	
2002	2	3	3	
2003	3	4	4	
2004	4	5	5	
2005	5	6	6	
2006	6	7	7	
2007	7	8	8	
2008	8	9	9	
2009	9	10	X	
2010	0	11	Y	
:	:	12	Z	

repeats in a 10 year cycle

Country of origin

Japan, Indonesia or Philippines (Indicated on the packing case)



■ Absolute Maximum Ratings $(T_a=25^{\circ}C)$ Parameter Symbol Rating Unit Forward current 50 I_{F} mA *1, 2Peak forward current $I_{FM} \\$ Α Input Reverse voltage V_R 6 V Power dissipation P 75 mWV Supply voltage $V_{CC} \\$ -0.5 to +17Output current 50 Output I_{O} mA Po 250 Power dissipation mW Operating temperature -25 to +85°C T_{opr} Storage temperature T_{stg} -40 to +100 °C °C *3Soldering temperature $T_{sol} \\$ 260

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

		Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
Lamust		Forward voltage	V_{F}	I _F =5mA	_	1.1	1.4	V
Input		Reverse current	I_R	$V_R=3V$	_	-	10	μΑ
	Operating supply voltage		V_{CC}	-	4.5	_	17	V
Output	Low level output voltage		V_{OL}	$V_{CC}=5V, I_{OL}=16mA, I_{F}=0$	_	0.15	0.4	V
	High level output voltage		V_{OH}	$V_{CC}=5V$, $I_F=5mA$	4.9	_	_	V
		Low level supply current	I_{CCL}	$V_{CC}=5V$, $I_F=0$	_	1.7	3.8	mA
		High level supply current	I_{CCH}	$V_{CC}=5V$, $I_F=5mA$	_	0.7	2.2	mA
*4 "Low→High" threshold input current		I_{FLH}	$V_{CC}=5V$	_	1	5	mA	
Transfer	*5	Hysteresis	$I_{\text{FHL}}/I_{\text{FLH}}$	$V_{CC}=5V$	0.55	0.75	0.95	_
charac- teristics	e 9*	"Low→High" Propagation delay time	t_{PLH}		_	3	9	
	e tin	"High→Low" Propagation delay time	High→Low" Propagation delay time t _{PHL}	$V_{CC}=5V$, $I_F=5mA$, $R_L=280\Omega$	_	5	15	μs
	ponc	Rise time	t _r	v CC=3 v, 1F=3111A, KL=200\$2	_	0.1	0.5	
	Res	Fall time	$t_{\rm f}$		_	0.05	0.5	

 $^{^*4~}I_{FLH}$ represents forward current when output goes from "Low" to "High".

^{*1} Refer to Fig. 1, 2, 3 *2 Pulse width \leq 100 μ s, Duty ratio=0.01

^{*3} For 5s or less

^{*5} I_{FHL} represents forward current when output goes from "High" to "Low".

^{*6} Test circuit for response time is shown in Fig.12.



Fig.1 Forward Current vs.

Ambient Temperature

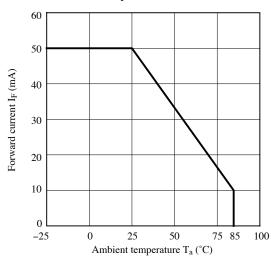


Fig.3 Low Level Output Current vs.
Ambient Temperature

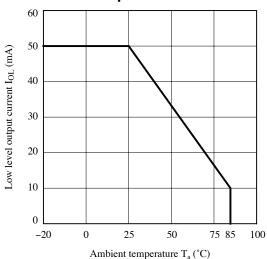


Fig.5 Relative Threshold Input Current vs. Supply Voltage

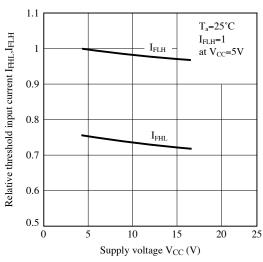


Fig.2 Output Power Dissipation vs. Ambient Temperature

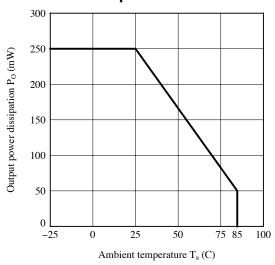


Fig.4 Forward Current vs. Forward Voltage

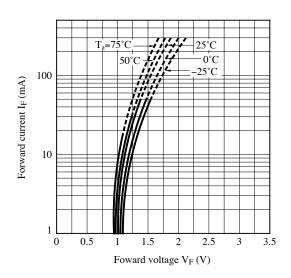


Fig.6 Relative Threshold Input Current vs. Ambient Temperature

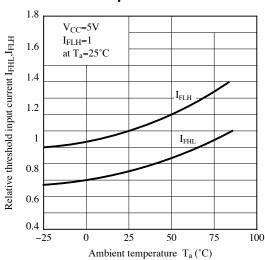




Fig.7 Low Level Output Voltage vs. Low Level Output Current

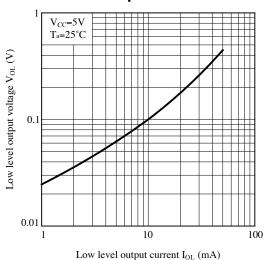


Fig.9 Supply Current vs.

Ambient Temperature (H Gain Mode)

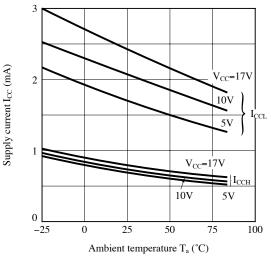


Fig.11 Rise Time,Fall Time vs. Load Resistance

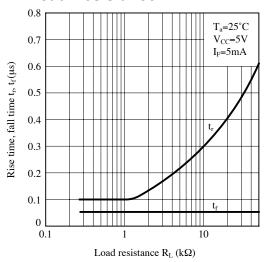


Fig.8 Low Level Output Voltage vs. Ambient Temperature

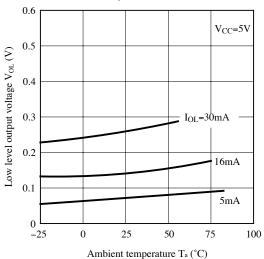


Fig.10 Propagation Delay Time vs. Forward Current

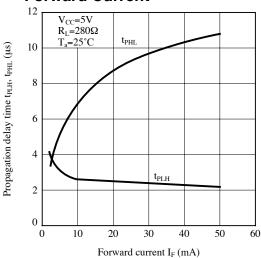
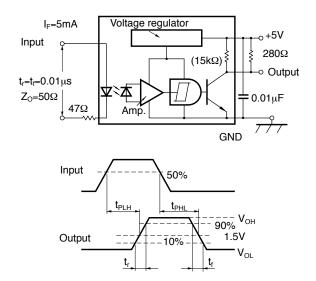


Fig.12 Test Circuit for Response Time



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Recommended operating conditions

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Output current	Io	_	-	16	mA
Forward current	I_{F}	10	_	20	mA
Operating terperature	Topr	0	-	70	°C

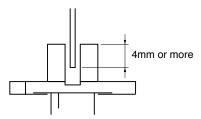
Notes about static electricity

Transisiter of detector side in bipolar configuration may be damaged by static electricity due to its minute design.

When handing these devices, general countermeasure against static electricity should be taken to avoid breakdown of devices or degradation of characteristics.

Design guide

- 1) Prevention of detection error
 - To prevent photointerrupter from faulty operation caused by external light, do not set the detecting face to the external light.
- 2) In order to stabilize power supply line, connect a by-pass capacitor of more than $0.01\mu F$ between V_{CC} and GND near the device.
- 3) Position of opaque board
 - Opaque board shall be installed at place 4mm or more from the top of elements. (Example)



This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.



Parts

This product is assembled using the below parts.

• Photodetector (qty. : 1) [Using a silicon photodiode as light detecting portion, and a bipolar IC as signal processing circuit]

Category	Maximum Sensitivity wavelength (nm)	Sensitivity wavelength (nm)	Response time (µs)
Photodiode	900	400 to 1 200	3

• Photo emitter (qty.: 1)

Category	Category Material		I/O Frequency (MHz)	
Infrared emitting diode (non-coherent)	Gallium arsenide (GaAs)	950	0.3	

Material

Case	Connector terminal flame finish
Black NORYL resin	Solder dip. (Sn-3Ag-0.5Cu)

Others

Laser generator is not used.



■ Manufacturing Guidelines

Soldering Method

Flow Soldering:

Soldering should be completed below 260°C and within 5 s.

Please take care not to let any external force exert on lead pins.

Please don't do soldering with preheating, and please don't do soldering by reflow.

Hand soldering

Hand soldering should be completed within 3 s when the point of solder iron is below 350°C.

Please solder within one time.

Please don't touch the terminals directly by soldering iron.

Soldered product shall treat at normal temperature.

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the cooling and soldering conditions.

Flux

Some flux, which is used in soldering, may crack the package due to synergistic effect of alcohol in flux and the rise in temperature by heat in soldering. Therefore, in using flux, please make sure that it does not have any influence on appearance and reliability of the photointerrupter.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning:

The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power output, cleaning time, PCB size or device mounting condition etc.

Please test it in actual using condition and confirm that doesn't occur any defect before starting the ultrasonic cleaning.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).



■ Package specification

Case package

Package materials

Anti-static plastic bag: Polyethtylene

Moltopren: Urethane

Partition: Corrugated fiberboard
Packing case: Corrugated fiberboard

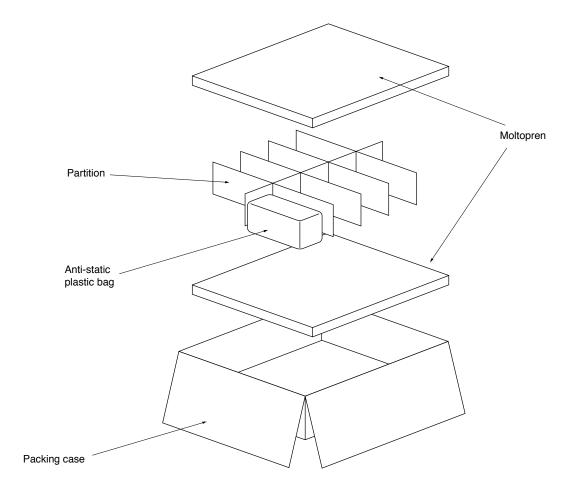
Package method

100 pcs of products shall be packaged in a plastic bag, Ends shall be fixed by stoppers. The bottom of the packing case is covered with moltopren, and the partition is set in the packing case. Each partition should have 1 plastic bag.

The 10 plastic bags containing a product are put in the packing case.

Moltopren should be located after all product are settled (1 packing contains 1 000 pcs).

Packing composition





■ Important Notices

- The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.
- · Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.
- · Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:
- (i) The devices in this publication are designed for use in general electronic equipment designs such as:
 - --- Personal computers
 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
- (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
 - --- Space applications
 - --- Telecommunication equipment [trunk lines]
 - --- Nuclear power control equipment
 - --- Medical and other life support equipment (e.g., scuba).
- · If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.
- This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.
- · Contact and consult with a SHARP representative if there are any questions about the contents of this publication.